

850nm 10Gb/s Multimode Flip Chip VCSEL Array

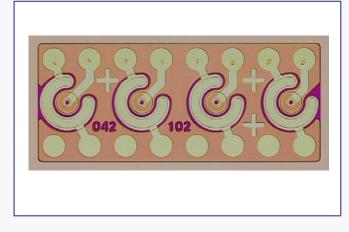
(Preliminary)

Features:

- 850nm multimode emission
- Low threshold and operation current
- High reliability
- Low electrical parasitics
- Data rates from DC to 10 Gb/s
- Flip chip bondable top contact configuration
- Common cathode electrodes
- Available as 4 or 12 channel array chip

Applications:

- Parallel fiber optical communication links
- Smart cables



Oclaro's high speed 850nm flip chip VCSEL array is designed to meet stringent specifications for parallel high speed data communication. The high performance, high reliability VCSEL array is engineered with low electrical parasitics for data rates up to 10Gb/s per channel. The common cathode configuration with cathode and anode contacts on the top side of the chip is ideal for flip chip packaging, but can also be used for wire bonding. The individual VCSELs of the array operate in multiple transverse and single longitudinal modes and emit circular symmetric beams with narrow divergence that can be efficiently coupled into 50/125 and 62.5/125 m multi-mode fibers. The VCSEL array is available in 4 or 12 channel configuration.

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Electro - Optical Characteristics*

| Parameter | Symbol | Conditions | Ratings | | | Unit | |
|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------------------|----------------------------------------------------|---------|-----|------|-------|--|
| raidilletei | Symbol | Conditions | Min | Тур | Max | Unit | |
| The section of the se | | T=25°C | 0.5 | 1.3 | 2.0 | mA | |
| Threshold current Ith | | T=85°C | 0.8 | 2.0 | 3.0 | mA | |
| Operating power | Pop | $I_{op} = 7mA$ | | 2.2 | | mW | |
| Slope efficiency | η | I=I _{th} +1mA | 0.2 | 0.4 | 0.6 | mW/mA | |
| Operating voltage | Uop | I _{op} = 7mA | | 2.0 | | V | |
| Differential resistance | Rd | I _{op} = 7mA | | 40 | 85 | W | |
| Emission wavelength | λ | I _{op} = 7mA, T=-10°C - 85°C | 840 | 850 | 860 | nm | |
| Spectral bandwidth, RMS | Δλ | I _{op} = 7mA | | 0.5 | 0.7 | nm | |
| Beam divergence | Q | l _{op} = 7mA, Full width 1/e ² | | 28 | 32 | 0 | |
| Capacitance | С | I _{op} = 7mA | | 0.4 | 0.7 | рF | |
| Modulation bandwidth | f _{3dB} | I _{op} = 7mA | 9 | | | GHz | |
| Rise/Fall time | tr | I _{op} = 7mA, ER=5dB, 20% - 80% | | 30 | 35 | ps | |
| | t _f | | | 40 | 45 | ps | |
| Relative intensity noise | RIN _{12(OM} | I _{op} = 7mA, ER=5dB, 7.73GHz BW | | | -128 | dB/Hz | |
| Threshold uniformity | Δlth | | | | 0.3 | mA | |
| Slope efficiency uniformity | Δη | | | | 0.1 | mW/mA | |

Thermal Characteristics

| Parameter | Symbol | Ratings | | | Unit | |
|-----------------------------------------|----------------|---------|------|-----|-------|--|
| raiailletei | Syllibol | Min | Тур | Max | Offic | |
| Temperature tuning co-efficient | δΙ/δΤ | | 0.06 | | nm/K | |
| Slope efficiency variation -10°C - 85°C | $\Delta\eta$ T | | -0.4 | | %/K | |
| Thermal impedance | Zth | | 2.0 | 2.5 | K/mW | |

^{*}T=25°C unless otherwise noted

Absolute Maximum Ratings

| Parameter | Rating | Unit |
|--------------------------------|-------------|------|
| Optical output power | 6 | mW |
| Peak forward current | 15 | mA |
| VCSEL reverse voltage | 5 | V |
| Operating temperature | -10 to +85 | °C |
| Storage temperature | -40 to +100 | °C |
| Mounting temperature (max. 1h) | 165 | °C |

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Mechanical Dimensions

| Parameter | Min | Тур | Max | Unit |
|---------------------------|------|------|------|------|
| Die length, APA4201040000 | 960 | 980 | 1000 | μm |
| Die length, APA4201120000 | 2960 | 2980 | 3000 | μm |
| Die width | 410 | 430 | 450 | μm |
| Die height | 185 | 200 | 215 | μm |



RoHS Compliance





Oclaro is fully committed to environment protection and sustainable development and has set in place a comprehensive program for removing polluting and hazardous substances from all of its products. The relevant evidence of RoHS compliance is held as part of our controlled documentation for each of our compliant products. RoHS compliance parts are available to order, please refer to the ordering information section for further details.

Ordering Information:

| Product Code | Data Rate | Description |
|---------------|-----------|-------------------------------------|
| APA4201040000 | 10Gb/s | 850nm MM 1x4 flip chip VCSEL array |
| APA4201120000 | 10Gb/s | 850nm MM 1x12 flip chip VCSEL array |

Contact Information

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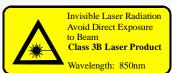
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Safety Labels





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